

UNISONIC TECHNOLOGIES CO., LTD

MGBR5U45

MOS GATED BARRIER RECTIFIER

DESCRIPTION

The UTC MGBR5U45 is a surface mount mos gated barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

FEATURES

* Ultra low forward voltage drop * High switching speed



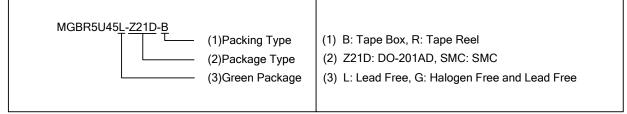


ORDERING INFORMATION

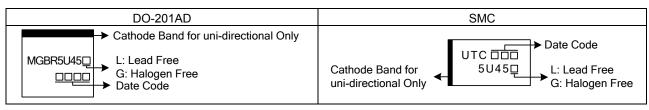
	DIODE
	1
2	DO-201AD
6	SMC (JEDEC DO-214AB)

Ordering Number		Deekage	Pin Assignment		Deaking	
Lead Free	Halogen Free	Package	1	2	Packing	
MGBR5U45L-Z21D-R	MGBR5U45G-Z21D-R	DO-201AD	К	А	Tape Box	
MGBR5U45L-SMC-R MGBR5U45G-SMC-R		SMC	К	А	Tape Reel	
Note: Pin Assignment: A: Anode K: Common Cathode						

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MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

T OF Capacitance load, derate current by 20	070.			
PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V _{RM}	45	V
Working Peak Reverse Voltage		V _{RWM}	45	V
Repetitive Peak Reverse Voltage		V _{RRM}	45	V
RMS Reverse Voltage		V _{R(RMS)}	35	V
Average Rectified Output Current	T _C =140°C	lo	5	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM}	200	А
Operating Junction Temperature		ΤJ	-65~+150	°C
Storage Temperature		T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL RESISTANCES CHARACTERISTICS

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient		θ _{JA}	75	°C/W	
Junction to Case	DO-201AD	0	15	°C/W	
	SMC	θ _{JC}	35	°C/W	

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R =0.5mA	45			V
Instantaneous Forward Voltage		I _F =5A, T _J =25°C			0.43	V
		I _F =5A, T _J =125°C			0.40	V
Leakage Current (Note 1)	RM	V _R =45V, T _J =25°C			500	μA
		V _R =45V, T _J =125°C			100	mA

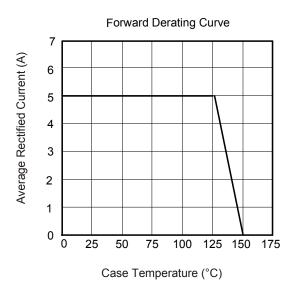
Notes: 1. Short duration pulse test used to minimize self-heating effect.

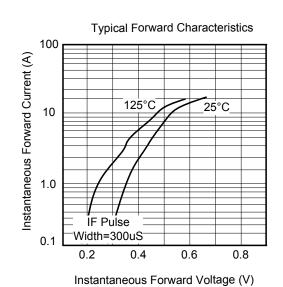
2. Thermal resistance junction to case mounted on heatsink.



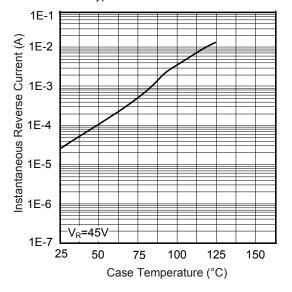
MGBR5U45

TYPICAL CHARACTERISTICS





Typical Reverse Characteristics



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